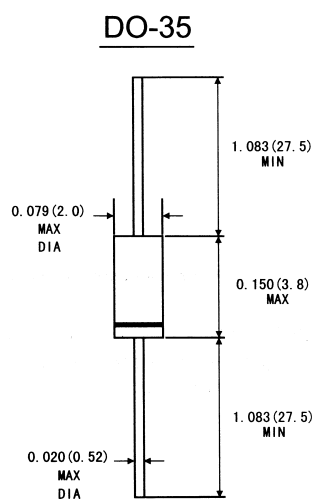


FEATURES

- Silicon planar power zener diodes
- Standards zener voltage tolerance is $\pm 10\%$. Add suffix "A" for $5\% \pm$ tolerance, other tolerance are available upon request

MECHANICAL DATA

- **Case:** DO-35 glass case
- **Polarity:** Color band denotes cathode end
- **Weight:** Approx. 0.13gram



Dimensions in inches and (millimeters)

ABSOLUTE MAXIMUM RATINGS(LIMITING VALUES)(TA=25°C)

	Symbols	Value	Units
Zener current see table "Characteristics"			
Power dissipation at TA=50°C	P _{tot}	500 ¹⁾	mW
Junction temperature	T _J	175	°C
Storage temperature range	T _{STG}	-65 to + 175	°C
1)Valid provided that at a distance of 8mm from case are kept at ambient temperature			

ELECTRICAL CHARACTERISTICS(TA=25°C)

	Symbols	Min.	Typ.	Max.	Units
Thermal resistance junction to ambient	R _{θJA}			300 ¹⁾	°C/W
Forward voltage at IF=200mA	V _F			1.5	
1)Valid provided that leads at a distance of 8mm from case are kept at ambient temperature					

1N746..1N759 SILICON PLANAR ZENER DIODES

Type	Zener Voltage Range ¹⁾		Maximum zener impedence Z _{ZR} at I _{ZR}	Typical Tempetature coefficient	Maximum Reverse Leakage Current I _R ²⁾ at V _R =1V		Maximum Regulator Current I _{ZM}		
	V _Z	I _{ZT}			T _A =25℃	T _A =150℃			
	V	mA			Ω	%/℃		μA	μ A
1N746	3.3	20	28	-0.062	10	30	110		
1N747	3.6		24	-0.055			100		
1N748	3.9		23	-0.049			95		
1N749	4.3		22	-0.036	2		85		
1N750	4.7		19	-0.018			75		
1N751	5.1		17	-0.008	1	20	70		
1N752	5.6		11	+0.006			65		
1N753	6.2		7	+0.022	0.1		60		
1N754	6.8		5	+0.035			55		
1N755	7.5		6	+0.045			50		
1N756	8.2		8	+0.052			45		
1N757	9.1		10	+0.056			40		
1N758	10.0		17	+0.060			35		
1N759	12.0		30	+0.060			30		
1)Tested with pulses t _p =20ms									
2)Valid provided that are kept at ambient temperature at a distance of 8mm from case.									